

Features

Collector Current: I_C=-0.6A

• Power Dissipation of 300mw



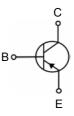
3. COLLECTOR



Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
HMMBT5401T	SOT-523	2L	3000

SOT-523



Maxmim Ratings (Ta=25 unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V _{CBO}	-160	V
Collector-Emitter Voltage	V _{CEO}	-150	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Current	I _c	-600	mA
Collector Power Dissipation	P _c	300	mW
Thermal Resistance From Junction To Ambient	R _{oJA}	416	°C/W
Junction Temperature	T _j	150	°C
Storage Temperature	T _{stg}	-55∼+150	$^{\circ}$

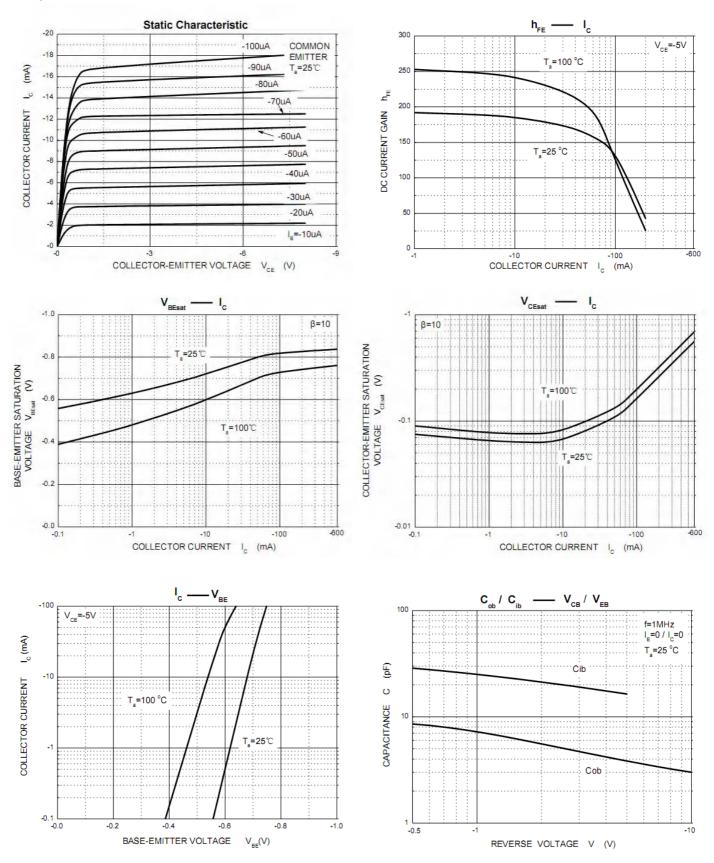
Electrcal Charcteristics (Ta=25 unless otherwise specified)

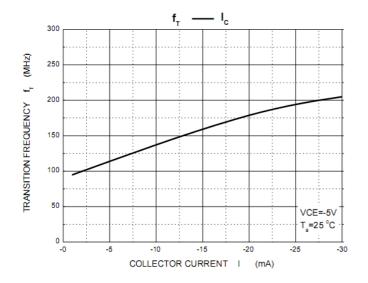
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =-100μA, I _E =0	-160			V
Collector-emitter breakdown voltage	V _{(BR)CEO} *	I _C =-1mA, I _B =0	-150			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I _E =-10μA, I _C =0	-5			V
Collector cut-off current	I _{CBO}	V _{CB} =-120V, I _E =0			-0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =-4V, I _C =0			-0.1	μA
DC current gain	h _{FE(1)} *	V _{CE} =-5V, I _C =-1mA	80			
	h _{FE(2)} *	V _{CE} =-5V, I _C =-10mA	100		300	
	h _{FE(3)} *	V _{CE} =-5V, I _C =-50mA	50			
Collector-emitter saturation voltage	$V_{CE(sat)1}^{\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ $	I _C =-10mA, I _B =-1mA			-0.2	V
	V _{CE(sat)2} *	I _C =-50mA, I _B =-5mA			-0.5	٧
Dana amittan antunation valtana	$V_{BE(sat)1}^{*}$	I _C =-10mA, I _B =-1mA			-1	V
Base-emitter saturation voltage	V _{BE(sat)2} *	I _C =-50mA, I _B =-5mA			-1	V
Transition frequency	f⊤	V _{CE} =-5V,I _C =-10mA, f=30MHz	100			MHz

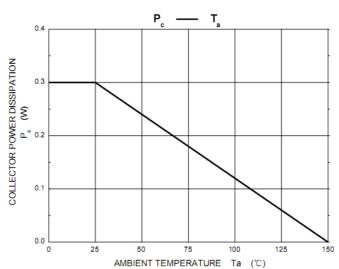
^{*}Pulse test: pulse width ≤300µs, duty cycle≤ 2.0%.



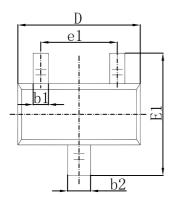
Typical Characteristics

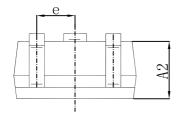


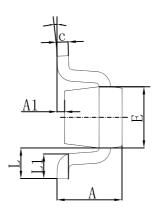




SOT-523 Package Information

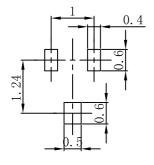






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	0.700	0.900	0.028	0.035	
A1	0.000	0.100	0.000	0.004	
A2	0.700	0.800	0.028	0.031	
b1	0.150	0.250	0.006	0.010	
b2	0.250	0.350	0.010	0.014	
С	0.100	0.200	0.004	0.008	
D	1.500	1.700	0.059	0.067	
E	0.700	0.900	0.028	0.035	
E1	1.450	1.750	0.057	0.069	
е	0.500	TYP.	0.020 TYP.		
e1	0.900	1.100	0.035	0.043	
L	0.400 REF.		0.016 REF.		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

SOT-523 Suggested Pad Layout



Note:

- 1. Controlling dimension: in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.



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